

50 kPa Uncompensated Silicon Pressure Sensors

The MPX53/MPXV53GC series silicon piezoresistive pressure sensors provide a very accurate and linear voltage output — directly proportional to the applied pressure. These standard, low cost, uncompensated sensors permit manufacturers to design and add their own external temperature compensating and signal conditioning networks. Compensation techniques are simplified because of the predictability of Freescale's single element strain gauge design.

Features

- Low Cost
- Patented Silicon Shear Stress Strain Gauge Design
- Ratiometric to Supply Voltage
- Easy to Use Chip Carrier Package Options
- 60 mV Span (Typ)
- Differential and Gauge Options

Typical Applications

- Air Movement Control
- Environmental Control Systems
- Level Indicators
- Leak Detection
- Medical Instrumentation
- Industrial Controls
- Pneumatic Control Systems
- Robotics

ORDERING INFORMATION

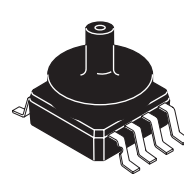
Device Type	Options	Case No.	MPX Series Order No.	Packing Options	Device Marking
SMALL OUTLINE PACKAGE ⁽¹⁾ (MPXV53 SERIES)					
Ported Elements	Gauge, Side Port, SMT	482A	MPXV53GC6T1	Tape & Rail	MPXV53G
		482A	MPXV53GC6U	Rails	MPXV53G
		482C	MPXV53GC7U	Rails	MPXV53G
UNIBODY PACKAGE ⁽²⁾ (MPX53 SERIES)					
Basic Element	Differential	344	MPX53D	—	MPX53D
Ported Elements	Differential	344C	MPX53DP	—	MPX53DP
	Gauge	344B	MPX53GP	—	MPX53GP

1. The MPXV53GC series pressure sensors are available with a pressure port, surface mount, or DIP leadforms and two packing options.
2. MPX53 series pressure sensors are available in differential and gauge configurations. Devices are available with basic element package or with pressure port fittings, providing printed circuit board mounting ease and barbed hose pressure.

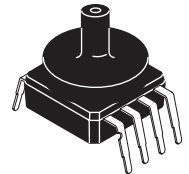
MPX53 MPXV53GC SERIES

UNCOMPENSATED PRESSURE SENSOR
0 TO 50 kPa (0 – 7.25 psi)
60 mV FULL SCALE SPAN
(TYPICAL)

SMALL OUTLINE PACKAGES



MPXV53GC6U
CASE 482A-01



MPXV53GC7U
CASE 482C-03

SMALL OUTLINE PACKAGE PIN NUMBERS

1	GND ⁽¹⁾	5	N/C
2	+V _{OUT}	6	N/C
3	V _S	7	N/C
4	-V _{OUT}	8	N/C

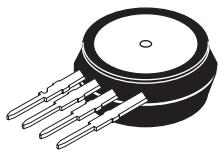
1. Pin 1 in noted by the notch in the lead.

UNIBODY PACKAGE PIN NUMBERS

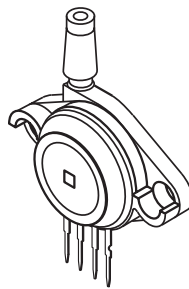
1	GND ⁽¹⁾	3	V _S
2	+V _{OUT}	4	-V _{OUT}

1. Pin 1 in noted by the notch in the lead.

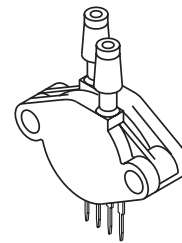
UNIBODY PACKAGES



MPX53D
CASE 344-15



MPX53GP
CASE 344B-01



MPX53DP
CASE 344C-01

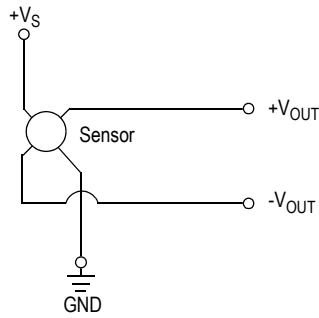


Figure 1. Uncompensated Pressure Sensor Schematic

VOLTAGE OUTPUT VERSUS APPLIED DIFFERENTIAL PRESSURE

The differential voltage output of the sensor is directly proportional to the differential the pressure side (P1) relative to the vacuum side (P2). Similarly, output voltage increases

as increasing vacuum is applied to the vacuum side (P2) relative to the pressure side (P1).

Figure 1 shows a schematic of the internal circuitry on the stand-alone pressure sensor chip.

Table 1. Maximum Ratings⁽¹⁾

Rating	Symbol	Value	Unit
Maximum Pressure (P1 > P2)	P_{MAX}	200	kPa
Storage Temperature	T_{STG}	-40 to +125	°C
Operating Temperature	T_A	-40 to +125	°C

1. Exposure beyond the specified limits may cause permanent damage or degradation to the device.

Table 2. Operating Characteristics ($V_S = 3.0$ Vdc, $T_A = 25^\circ\text{C}$ unless otherwise noted, $P1 > P2$)

Characteristic	Symbol	Min	Typ	Max	Units
Pressure Range ⁽¹⁾	P_{OP}	0	—	50	kPa
Supply Voltage ⁽²⁾	V_S	—	3.0	6.0	V_{DC}
Supply Current	I_O	—	6.0	—	mAdc
Full Scale Span ⁽³⁾	V_{FSS}	45	60	90	mV
Offset ⁽⁴⁾	V_{OFF}	0	20	35	mV
Sensitivity	$\Delta V/\Delta P$	—	1.2	—	mV/kPa
Linearity ⁽⁵⁾	—	-0.6	—	0.4	% V_{FSS}
Pressure Hysteresis ⁽⁵⁾ (0 to 50 kPa)	—	—	± 0.1	—	% V_{FSS}
Temperature Hysteresis ⁽⁵⁾ (-40°C to $+125^\circ\text{C}$)	—	—	± 0.5	—	% V_{FSS}
Temperature Coefficient of Full Scale Span ⁽⁵⁾	TCV_{FSS}	-0.22	—	-0.16	% $V_{FSS}/^\circ\text{C}$
Temperature Coefficient of Offset ⁽⁵⁾	TCV_{OFF}	—	± 15	—	$\mu\text{V}/^\circ\text{C}$
Temperature Coefficient of Resistance ⁽⁵⁾	TCR	0.31	—	0.37	% $Z_{IN}/^\circ\text{C}$
Input Impedance	Z_{IN}	355	—	505	Ω
Output Impedance	Z_{OUT}	750	—	1875	Ω
Response Time ⁽⁶⁾ (10% to 90%)	t_R	—	1.0	—	ms
Warm-Up Time	—	—	2.0	—	ms
Offset Stability ⁽⁷⁾	—	—	± 0.5	—	% V_{FSS}

- 1.0 kPa (kiloPascal) equals 0.145 psi.
- Device is ratiometric within this specified excitation range. Operating the device above the specified excitation range may induce additional error due to device self-heating.
- Full Scale Span (V_{FSS}) is defined as the algebraic difference between the output voltage at full rated pressure and the output voltage at the minimum related pressure.
- Offset (V_{OFF}) is defined as the output voltage at the minimum rated pressure.
- Accuracy (error budget) consists of the following:
 - Linearity: Output deviation from a straight line relationship with pressure over the specified pressure range.
 - Temperature Hysteresis: Output deviation at any temperature within the operating temperature range, after the temperature is cycled to and from the minimum or maximum operating temperature points, with zero differential pressure applied.
 - Pressure Hysteresis: Output deviation at any pressure within the specified range, when this pressure is cycled to and from the minimum or maximum rated pressure, at 25°C .
 - TcSpan: Output deviation over the temperature range of 0° to 85°C , relative to 25°C .
 - TcOffset: Output deviation with minimum rated pressure applied, over the temperature range of 0° to 85°C , relative to 25°C .
 - Variation from Nominal: The variation from nominal values, for Offset or Full Scale Span, as a percent of V_{FSS} , at 25°C .
- Response Time is defined as the time from the incremental change in the output to go from 10% to 90% of its final value when subjected to a specified step change in pressure.
- Offset stability is the product's output deviation when subjected to 1000 hours of Pulsed Pressure, Temperature Cycling with Bias Test.

TEMPERATURE COMPENSATION

Figure 2 shows the typical output characteristics of the MPX53/MPXV53GC series over temperature.

The piezoresistive pressure sensor element is a semiconductor device which gives an electrical output signal proportional to the pressure applied to the device. This device uses a unique transverse voltage diffused semiconductor strain gauge which is sensitive to stresses produced in a thin silicon diaphragm by the applied pressure.

Because this strain gauge is an integral part of the silicon diaphragm, there are no temperature effects due to differences in the thermal expansion of the strain gauge and

the diaphragm, as are often encountered in bonded strain gauge pressure sensors. However, the properties of the strain gauge itself are temperature dependent, requiring that the device be temperature compensated if it is to be used over an extensive temperature range.

Temperature compensation and offset calibration can be achieved rather simply with additional resistive components, or by designing your system using the MPX2053 series sensors.

Several approaches to external temperature compensation over both -40 to $+125^{\circ}\text{C}$ and 0 to $+80^{\circ}\text{C}$ ranges are presented in Freescale Application Note AN840.

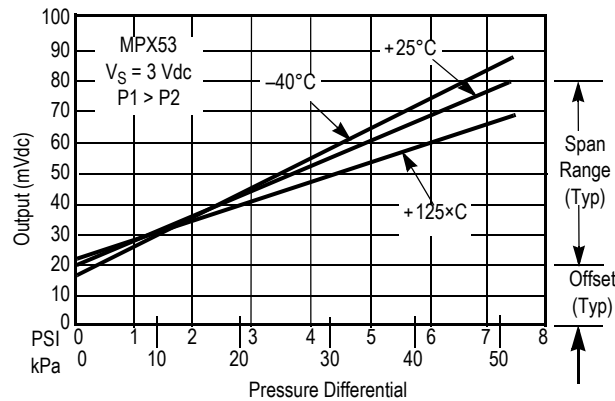


Figure 2. Output vs. Pressure Differential

LINEARITY

Linearity refers to how well a transducer's output follows the equation: $V_{\text{out}} = V_{\text{off}} + \text{sensitivity} \times P$ over the operating pressure range (see Figure 3). There are two basic methods for calculating nonlinearity: (1) end point straight line fit or (2) a least squares best line fit. While a least squares fit gives the "best case" linearity error (lower numerical value), the calculations required are burdensome.

Conversely, an end point fit will give the "worst case" error (often more desirable in error budget calculations) and the calculations are more straightforward for the user. Freescale's specified pressure sensor linearities are based on the end point straight line method measured at the midrange pressure.

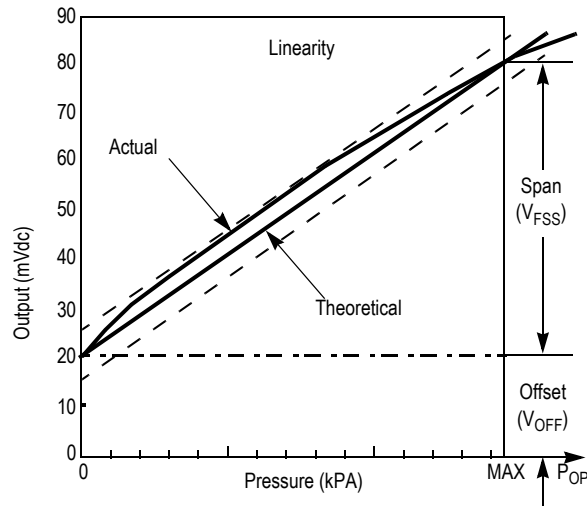


Figure 3. Linearity Specification Comparison

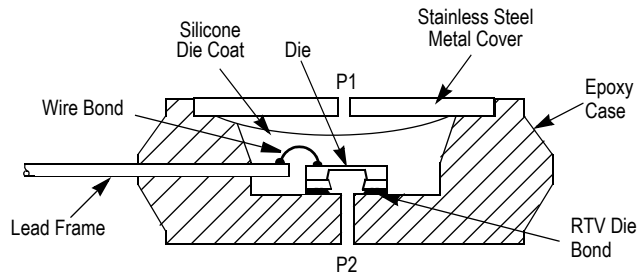


Figure 4. Unibody Package: Cross Sectional Diagram (Not to Scale)

Figure 4 illustrates the differential or gauge configuration in the unibody chip carrier (Case 344). A silicone gel isolates the die surface and wire bonds from the environment, while allowing the pressure signal to be transmitted to the silicon diaphragm.

The MPX53/MPXV53GC series pressure sensor operating characteristics and internal reliability and qualification tests are based on use of dry air as the pressure media. Media other than dry air may have adverse effects on sensor performance and long term reliability. Contact the factory for information regarding media compatibility in your application.

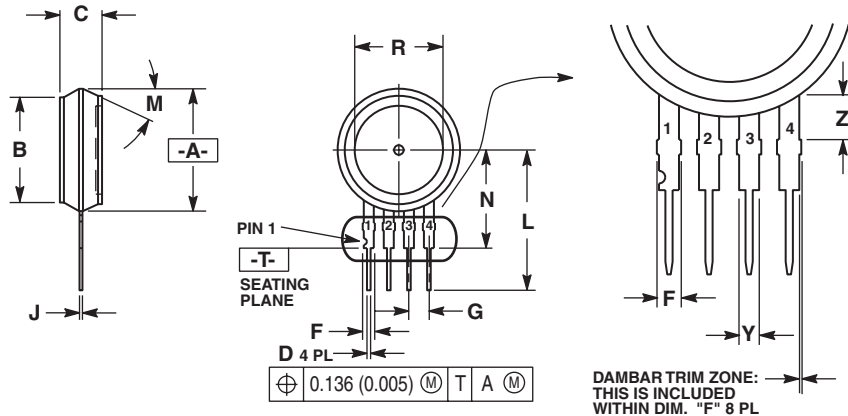
PRESSURE (P1)/VACUUM (P2) SIDE IDENTIFICATION TABLE

Freescale designates the two sides of the pressure sensor as the Pressure (P1) side and the Vacuum (P2) side. The Pressure (P1) side is the side containing silicone gel which isolates the die from the environment. The Freescale MPX pressure sensor is designed to operate with positive differential pressure applied, $P1 > P2$.

The Pressure (P1) side may be identified by using the following table.

Part Number	Case Type	Pressure (P1) Side Identifier
MPX53D	344	Stainless Steep Cap
MPX53DP	344C	Side with Port Marking
MPX53GP	344B	Side with Port Attached
MPX53GC Series	482A, 482C	Side with Port Attached

PACKAGE DIMENSIONS



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION -A- IS INCLUSIVE OF THE MOLD STOP RING. MOLD STOP RING NOT TO EXCEED 16.00 (0.630).

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.595	0.630	15.11	16.00
B	0.514	0.534	13.06	13.56
C	0.200	0.220	5.08	5.59
D	0.016	0.020	0.41	0.51
F	0.048	0.064	1.22	1.63
G	0.100 BSC		2.54 BSC	
J	0.014	0.016	0.36	0.40
L	0.695	0.725	17.65	18.42
M	30' NOM		30' NOM	
N	0.475	0.495	12.07	12.57
R	0.430	0.450	10.92	11.43
Y	0.048	0.052	1.22	1.32
Z	0.106	0.118	2.68	3.00

STYLE 1:

1. GROUND
2. + OUTPUT
3. + SUPPLY
4. - OUTPUT

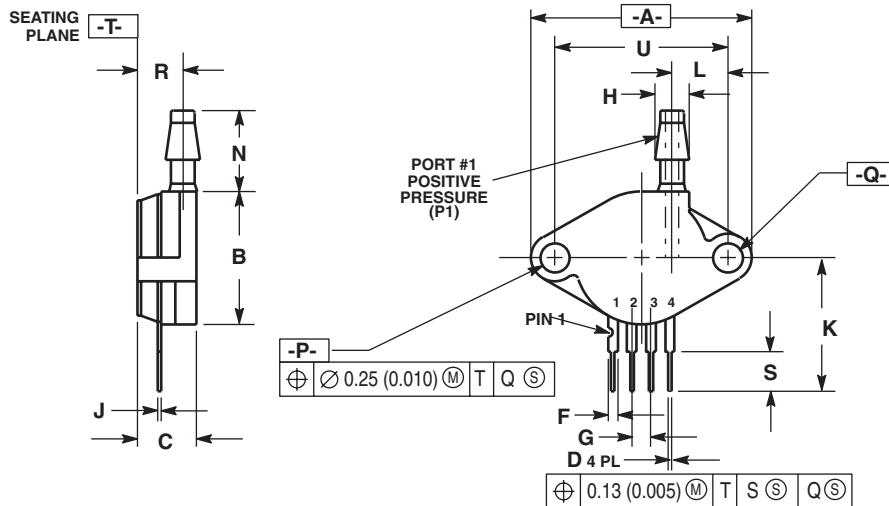
STYLE 2:

1. V_{CC}
2. - SUPPLY
3. + SUPPLY
4. GROUND

STYLE 3:

1. GND
2. -VOUT
3. VS
4. +VOUT

CASE 344-15 ISSUE AA UNIBODY PACKAGE



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

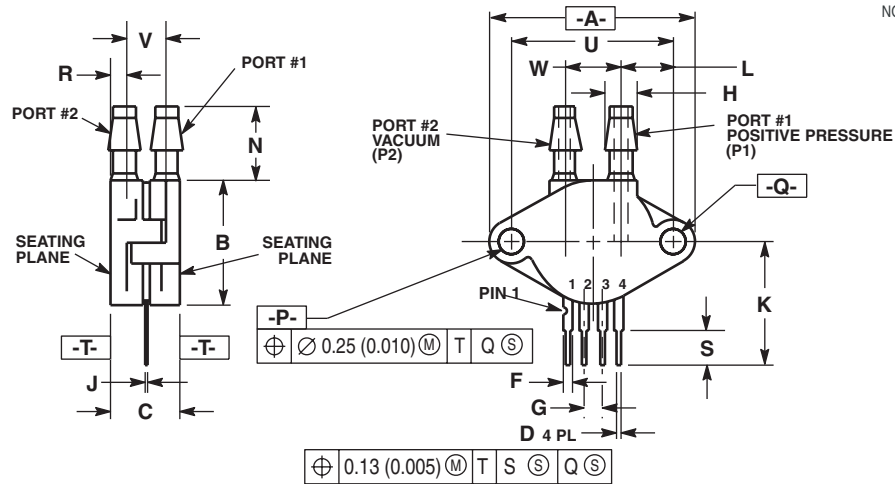
DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.145	1.175	29.08	29.85
B	0.685	0.715	17.40	18.16
C	0.305	0.325	7.75	8.26
D	0.016	0.020	0.41	0.51
F	0.048	0.064	1.22	1.63
G	0.100 BSC		2.54 BSC	
H	0.182	0.194	4.62	4.93
J	0.014	0.016	0.36	0.41
K	0.695	0.725	17.65	18.42
L	0.290	0.300	7.37	7.62
N	0.420	0.440	10.67	11.18
P	0.153	0.159	3.89	4.04
Q	0.153	0.159	3.89	4.04
R	0.230	0.250	5.84	6.35
S	0.220	0.240	5.59	6.10
U	0.910 BSC		23.11 BSC	

STYLE 1:

1. GROUND
2. + OUTPUT
3. + SUPPLY
4. - OUTPUT

CASE 344B-01 ISSUE B UNIBODY PACKAGE

PACKAGE DIMENSIONS



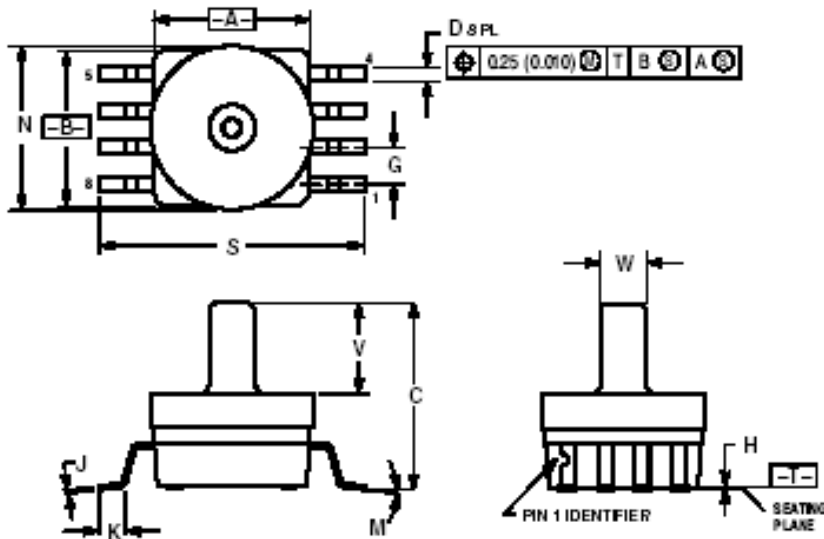
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.145	1.175	29.08	29.85
B	0.685	0.715	17.40	18.16
C	0.405	0.435	10.29	11.05
D	0.016	0.020	0.41	0.51
F	0.048	0.064	1.22	1.63
G	0.100 BSC		2.54 BSC	
H	0.182	0.194	4.62	4.93
J	0.014	0.016	0.36	0.41
K	0.695	0.725	17.65	18.42
L	0.290	0.300	7.37	7.62
N	0.420	0.440	10.67	11.18
P	0.153	0.159	3.89	4.04
Q	0.153	0.159	3.89	4.04
R	0.063	0.083	1.60	2.11
S	0.220	0.240	5.59	6.10
U	0.910 BSC		23.11 BSC	
V	0.248	0.278	6.30	7.06
W	0.310	0.330	7.87	8.38

- STYLE 1:
 PIN 1. GROUND
 2. + OUTPUT
 3. + SUPPLY
 4. - OUTPUT

CASE 344C-01 ISSUE B UNIBODY PACKAGE

PACKAGE DIMENSIONS

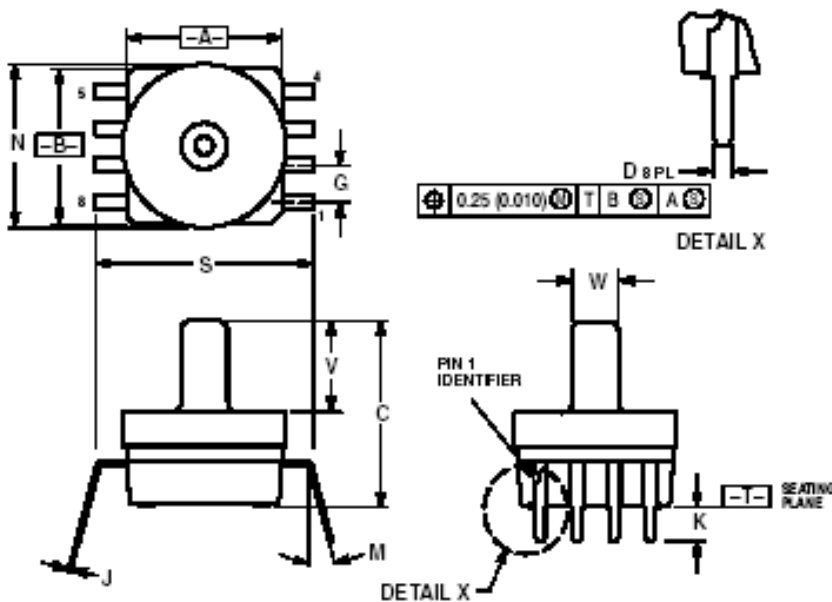


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006).
5. ALL VERTICAL SURFACES 5° TYPICAL DRAFT.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.415	0.425	10.54	10.79
B	0.415	0.425	10.54	10.79
C	0.500	0.520	12.70	13.21
D	0.028	0.042	0.66	1.07
G	0.100 BSC		2.54 BSC	
H	0.002	0.010	0.05	0.25
J	0.009	0.011	0.23	0.28
K	0.061	0.071	1.55	1.80
M	0°	7°	0°	7°
N	0.444	0.448	11.28	11.38
S	0.709	0.725	18.01	18.41
V	0.245	0.255	6.22	6.48
W	0.115	0.125	2.92	3.17

CASE 482A-01
ISSUE A
SMALL OUTLINE PACKAGE



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006).
5. ALL VERTICAL SURFACES 5° TYPICAL DRAFT.
6. DIMENSIONS TO CENTER OF LEAD WHEN FORMED PARALLEL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.415	0.425	10.54	10.79
B	0.415	0.425	10.54	10.79
C	0.500	0.520	12.70	13.21
D	0.028	0.034	0.66	0.864
G	0.100 BSC		2.54 BSC	
J	0.009	0.011	0.23	0.28
K	0.100	0.120	2.54	3.05
M	0°	15°	0°	15°
N	0.444	0.448	11.28	11.38
S	0.540	0.560	13.72	14.22
V	0.245	0.255	6.22	6.48
W	0.115	0.125	2.92	3.17

CASE 482C-03
ISSUE B
SMALL OUTLINE PACKAGE

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